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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details

Product Status	Active
Number of LABs/CLBs	75072
Number of Logic Elements/Cells	1313763
Total RAM Bits	190976000
Number of I/O	702
Number of Gates	-
Voltage - Supply	0.873V ~ 0.927V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 100°C (Tj)
Package / Case	2104-BBGA, FCBGA
Supplier Device Package	2104-FCBGA (47.5x47.5)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcvu5p-3flvb2104e

Recommended Operating Conditions

Table 2: Recommended Operating Conditions⁽¹⁾⁽²⁾

Symbol	Description	Min	Typ	Max	Units
FPGA Logic					
V_{CCINT}	Internal supply voltage.	0.825	0.850	0.876	V
	For -2LE ($V_{CCINT} = 0.72V$) devices: internal supply voltage.	0.698	0.720	0.742	V
	For -3E devices: internal supply voltage.	0.873	0.900	0.927	V
$V_{CCINT_IO}^{(3)}$	Internal supply voltage for the I/O banks.	0.825	0.850	0.876	V
	For -2LE devices ($V_{CCINT} = 0.85V$): internal supply voltage for the I/O banks.	0.825	0.850	0.876	V
	For -3E devices: internal supply voltage for the I/O banks.	0.873	0.900	0.927	V
V_{CCBRAM}	Block RAM supply voltage.	0.825	0.850	0.876	V
	For -3E devices: block RAM supply voltage.	0.873	0.900	0.927	V
V_{CCAUX}	Auxiliary supply voltage.	1.746	1.800	1.854	V
$V_{CCO}^{(4)(5)}$	Supply voltage for I/O banks.	0.950	–	1.900	V
$V_{CCAUX_IO}^{(6)}$	Auxiliary I/O supply voltage.	1.746	1.800	1.854	V
$V_{IN}^{(7)}$	I/O input voltage.	-0.200	–	$V_{CCO} + 0.200$	V
$I_{IN}^{(8)}$	Maximum current through any pin in a powered or unpowered bank when forward biasing the clamp diode.	–	–	10	mA
$V_{BATT}^{(9)}$	Battery voltage.	1.000	–	1.890	V
GTY Transceiver					
$V_{MGTAVCC}^{(10)}$	Analog supply voltage for the GTY transceiver.	0.873	0.900	0.927	V
$V_{MGTAVTT}^{(10)}$	Analog supply voltage for the GTY transmitter and receiver termination circuits.	1.164	1.20	1.236	V
$V_{MGTVCCAUX}^{(10)}$	Auxiliary analog QPLL voltage supply for the transceivers.	1.746	1.80	1.854	V
$V_{MGTAVTRCAL}^{(10)}$	Analog supply voltage for the resistor calibration circuit of the GTY transceiver column.	1.164	1.20	1.236	V

Table 13: DC Output Levels for Single-ended and Differential POD10 and POD12 Standards⁽¹⁾⁽²⁾

Symbol	Description	V _{OUT}	Min	Typ	Max	Units
R _{OL}	Pull-down resistance.	V _{OM_DC} (as described in Table 14)	36	40	44	Ω
R _{OH}	Pull-up resistance.	V _{OM_DC} (as described in Table 14)	36	40	44	Ω

Notes:

1. Tested according to relevant specifications.
2. Standards specified using the default I/O standard configuration. For details, see the *UltraScale Architecture SelectIO Resources User Guide* ([UG571](#)).

Table 14: Table 13 Definitions for DC Output Levels for POD Standards

Symbol	Description	All Speed Grades	Units
V _{OM_DC}	DC output Mid measurement level (for IV curve linearity).	0.8 × V _{CCO}	V

LVDS DC Specifications (LVDS)

Table 15: LVDS DC Specifications

Symbol	DC Parameter	Conditions	Min	Typ	Max	Units
V _{CCO} ⁽¹⁾	Supply voltage.		1.710	1.800	1.890	V
V _{ODIFF} ⁽²⁾	Differential output voltage: (Q – Q̄), Q = High (Q – Q̄), Q̄ = High	R _T = 100Ω across Q and Q̄ signals	247	350	454	mV
V _{OCM} ⁽²⁾	Output common-mode voltage.	R _T = 100 Ω across Q and Q̄ signals	1.000	1.250	1.425	V
V _{IDIFF}	Differential input voltage: (Q – Q̄), Q = High (Q – Q̄), Q̄ = High		100	350	600 ⁽³⁾	mV
V _{ICM_DC} ⁽⁴⁾	Input common-mode voltage (DC coupling).		0.300	1.200	1.425	V
V _{ICM_AC} ⁽⁵⁾	Input common-mode voltage (AC coupling).		0.600	–	1.100	V

Notes:

1. In I/O banks, when LVDS is used with input-only functionality, it can be placed in a bank where the V_{CCO} levels are different from the specified level only if internal differential termination is not used. In this scenario, V_{CCO} must be chosen to ensure the input pin voltage levels do not violate the *Recommended Operating Condition* (Table 2) specification for the V_{IN} I/O pin voltage.
2. V_{OCM} and V_{ODIFF} values are for LVDS_PRE_EMPHASIS = FALSE.
3. Maximum V_{IDIFF} value is specified for the maximum V_{ICM} specification. With a lower V_{ICM}, a higher V_{IDIFF} is tolerated only when the recommended operating conditions and overshoot/undershoot V_{IN} specifications are maintained.
4. Input common mode voltage for DC coupled configurations. EQUALIZATION = EQ_NONE (Default).
5. External input common mode voltage specification for AC coupled configurations. EQUALIZATION = EQ_LEVEL0, EQ_LEVEL1, EQ_LEVEL2, EQ_LEVEL3, EQ_LEVEL4.

Speed Grade Designations

Since individual family members are produced at different times, the migration from one category to another depends completely on the status of the fabrication process for each device. [Table 16](#) correlates the current status of the Virtex UltraScale+ FPGA on a per speed grade basis.

Table 17: Speed Grade Designations by Device

Device	Speed Grade, Temperature Ranges, and V_{CCINT} Operating Voltages		
	Advance	Preliminary	Production
XCVU3P	-3E ($V_{CCINT} = 0.90V$) -2LE ($V_{CCINT} = 0.85V$) -2LE ($V_{CCINT} = 0.72V$) ⁽¹⁾		-2I ($V_{CCINT} = 0.85V$) -1E ($V_{CCINT} = 0.85V$) -1I ($V_{CCINT} = 0.85V$)
XCVU5P	-3E ($V_{CCINT} = 0.90V$) -2I ($V_{CCINT} = 0.85V$), -2LE ($V_{CCINT} = 0.85V$) -1E ($V_{CCINT} = 0.85V$), -1I ($V_{CCINT} = 0.85V$) -2LE ($V_{CCINT} = 0.72V$) ⁽¹⁾		
XCVU7P	-3E ($V_{CCINT} = 0.90V$) -2I ($V_{CCINT} = 0.85V$), -2LE ($V_{CCINT} = 0.85V$) -1E ($V_{CCINT} = 0.85V$), -1I ($V_{CCINT} = 0.85V$) -2LE ($V_{CCINT} = 0.72V$) ⁽¹⁾		
XCVU9P	-3E ($V_{CCINT} = 0.90V$) -2I ($V_{CCINT} = 0.85V$), -2LE ($V_{CCINT} = 0.85V$) -1E ($V_{CCINT} = 0.85V$), -1I ($V_{CCINT} = 0.85V$) -2LE ($V_{CCINT} = 0.72V$) ⁽¹⁾		
XCVU11P	-3E ($V_{CCINT} = 0.90V$) -2I ($V_{CCINT} = 0.85V$), -2LE ($V_{CCINT} = 0.85V$) -1E ($V_{CCINT} = 0.85V$), -1I ($V_{CCINT} = 0.85V$), -2LE ($V_{CCINT} = 0.72V$) ⁽¹⁾		
XCVU13P	-3E ($V_{CCINT} = 0.90V$) -2I ($V_{CCINT} = 0.85V$), -2LE ($V_{CCINT} = 0.85V$) -1E ($V_{CCINT} = 0.85V$), -1I ($V_{CCINT} = 0.85V$) -2LE ($V_{CCINT} = 0.72V$) ⁽¹⁾		

Notes:

1. The lowest power -2L devices, where $V_{CCINT} = 0.72V$, are listed in the Vivado Design Suite as -2LV.

Production Silicon and Software Status

In some cases, a particular family member (and speed grade) is released to production before a speed specification is released with the correct label (Advance, Preliminary, Production). Any labeling discrepancies are corrected in subsequent speed specification releases.

Table 18 lists the production released Virtex UltraScale+ FPGA, speed grade, and the minimum corresponding supported speed specification version and Vivado software revisions. The Vivado software and speed specifications listed are the minimum releases required for production. All subsequent releases of software and speed specifications are valid.

Table 18: Virtex UltraScale+ FPGA Device Production Software and Speed Specification Release

Device	Speed Grade and V _{CCINT} Operating Voltages			
	0.90V	0.85V		0.72V
	-3	-2	-1	-2L
XCVU3P		Vivado tools 2017.1 v1.10		
XCVU5P				
XCVU7P				
XCVU9P				
XCVU11P				
XCVU13P				

Notes:

1. Blank entries indicate a device and/or speed grade in Advance or Preliminary status.

Table 22: LVDS Native-Mode 1000BASE-X Support⁽¹⁾

Description	Speed Grade and V _{CCINT} Operating Voltages			
	0.90V	0.85V		0.72V
	-3	-2	-1	-2
1000BASE-X	Yes			

Notes:

1. 1000BASE-X support is based on the *IEEE Standard for CSMA/CD Access Method and Physical Layer Specifications* (IEEE Std 802.3-2008).

Table 23 provides the maximum data rates for applicable memory standards using the Virtex UltraScale+ FPGA memory PHY. Refer to [Memory Interfaces](#) for the complete list of memory interface standards supported and detailed specifications. The final performance of the memory interface is determined through a complete design implemented in the Vivado Design Suite, following guidelines in the *UltraScale Architecture PCB Design Guide* ([UG583](#)), electrical analysis, and characterization of the system.

Table 23: Maximum Physical Interface (PHY) Rate for Memory Interfaces

Memory Standard	DRAM Type	Speed Grade and V _{CCINT} Operating Voltages				Units
		0.90V	0.85V		0.72V	
		-3	-2	-1	-2	
DDR4	Single rank component	2666	2666	2400	2400	Mb/s
	1 rank DIMM ⁽¹⁾⁽²⁾	2400	2400	2133	2133	Mb/s
	2 rank DIMM ⁽¹⁾⁽³⁾	2133	2133	1866	1866	Mb/s
	4 rank DIMM ⁽¹⁾⁽⁴⁾	1600	1600	1333	1333	Mb/s
DDR3	Single rank component	2133	2133	2133	2133	Mb/s
	1 rank DIMM ⁽¹⁾⁽²⁾	1866	1866	1866	1866	Mb/s
	2 rank DIMM ⁽¹⁾⁽³⁾	1600	1600	1600	1600	Mb/s
	4 rank DIMM ⁽¹⁾⁽⁴⁾	1066	1066	1066	1066	Mb/s
DDR3L	Single rank component	1866	1866	1866	1866	Mb/s
	1 rank DIMM ⁽¹⁾⁽²⁾	1600	1600	1600	1600	Mb/s
	2 rank DIMM ⁽¹⁾⁽³⁾	1333	1333	1333	1333	Mb/s
	4 rank DIMM ⁽¹⁾⁽⁴⁾	800	800	800	800	Mb/s
QDR II+	Single rank component ⁽⁵⁾	633	633	600	600	MHz
RLDRAM 3	Single rank component	1200	1200	1066	1066	MHz
QDR IV XP	Single rank component	1066	1066	1066	933	MHz
LPDDR3	Single rank component	1600	1600	1600	1600	Mb/s

Notes:

1. Dual in-line memory module (DIMM) includes RDIMM, SODIMM, UDIMM, and LRDIMM.
2. Includes: 1 rank 1 slot, DDP 2 rank, LRDIMM 2 or 4 rank 1 slot.
3. Includes: 2 rank 1 slot, 1 rank 2 slot, LRDIMM 2 rank 2 slot.
4. Includes: 2 rank 2 slot, 4 rank 1 slot.
5. The QDRII+ performance specifications are for burst-length 4 (BL = 4) implementations.

Table 24: IOB High Performance (HP) Switching Characteristics (Cont'd)

I/O Standards	T _{INBUF_DELAY_PAD_I}			T _{OUTBUF_DELAY_O_PAD}			T _{OUTBUF_DELAY_TD_PAD}			Units			
	0.90V	0.85V	0.72V	0.90V	0.85V	0.72V	0.90V	0.85V	0.72V				
	-3	-2	-1	-2	-3	-2	-1	-2	-3				
DIFF POD10 DCI_F	0.411	0.411	0.430	0.411	0.425	0.425	0.444	0.425	0.555	0.555	0.584	0.555	ns
DIFF POD10 DCI_M	0.411	0.411	0.430	0.411	0.542	0.542	0.571	0.542	0.640	0.640	0.681	0.640	ns
DIFF POD10 DCI_S	0.411	0.411	0.430	0.411	0.754	0.754	0.815	0.754	0.850	0.850	0.917	0.850	ns
DIFF POD10 F	0.411	0.411	0.433	0.411	0.438	0.438	0.459	0.438	0.569	0.569	0.601	0.569	ns
DIFF POD10 M	0.411	0.411	0.433	0.411	0.538	0.538	0.568	0.538	0.630	0.630	0.667	0.630	ns
DIFF POD10 S	0.411	0.411	0.433	0.411	0.766	0.766	0.821	0.766	0.836	0.836	0.894	0.836	ns
DIFF POD12 DCI_F	0.407	0.407	0.432	0.407	0.425	0.425	0.443	0.425	0.558	0.558	0.586	0.558	ns
DIFF POD12 DCI_M	0.407	0.407	0.432	0.407	0.543	0.543	0.572	0.543	0.638	0.638	0.678	0.638	ns
DIFF POD12 DCI_S	0.407	0.407	0.432	0.407	0.772	0.772	0.822	0.772	0.862	0.862	0.929	0.862	ns
DIFF POD12 F	0.409	0.409	0.430	0.409	0.455	0.455	0.476	0.455	0.595	0.595	0.626	0.595	ns
DIFF POD12 M	0.409	0.409	0.430	0.409	0.551	0.551	0.582	0.551	0.641	0.641	0.679	0.641	ns
DIFF POD12 S	0.409	0.409	0.430	0.409	0.767	0.767	0.817	0.767	0.832	0.832	0.889	0.832	ns
DIFF SSTL12 DCI_F	0.381	0.381	0.400	0.381	0.425	0.425	0.443	0.425	0.558	0.558	0.586	0.558	ns
DIFF SSTL12 DCI_M	0.381	0.381	0.400	0.381	0.557	0.557	0.587	0.557	0.654	0.654	0.694	0.654	ns
DIFF SSTL12 DCI_S	0.381	0.381	0.400	0.381	0.754	0.754	0.803	0.754	0.842	0.842	0.908	0.842	ns
DIFF SSTL12 F	0.394	0.394	0.402	0.394	0.412	0.412	0.430	0.412	0.538	0.538	0.566	0.538	ns
DIFF SSTL12 M	0.394	0.394	0.402	0.394	0.553	0.553	0.584	0.553	0.641	0.641	0.676	0.641	ns
DIFF SSTL12 S	0.394	0.394	0.402	0.394	0.758	0.758	0.808	0.758	0.823	0.823	0.879	0.823	ns
DIFF SSTL135 DCI_F	0.371	0.371	0.402	0.371	0.411	0.411	0.428	0.411	0.537	0.537	0.565	0.537	ns
DIFF SSTL135 DCI_M	0.371	0.371	0.402	0.371	0.551	0.551	0.582	0.551	0.645	0.645	0.685	0.645	ns
DIFF SSTL135 DCI_S	0.371	0.371	0.402	0.371	0.746	0.746	0.799	0.746	0.829	0.829	0.893	0.829	ns
DIFF SSTL135 F	0.375	0.375	0.402	0.375	0.408	0.408	0.428	0.408	0.528	0.528	0.561	0.528	ns
DIFF SSTL135 M	0.375	0.375	0.402	0.375	0.555	0.555	0.585	0.555	0.641	0.641	0.679	0.641	ns
DIFF SSTL135 S	0.375	0.375	0.402	0.375	0.772	0.772	0.823	0.772	0.827	0.827	0.878	0.827	ns
DIFF SSTL15 DCI_F	0.397	0.397	0.417	0.397	0.412	0.412	0.429	0.412	0.531	0.531	0.563	0.531	ns
DIFF SSTL15 DCI_M	0.397	0.397	0.417	0.397	0.553	0.553	0.583	0.553	0.645	0.645	0.685	0.645	ns
DIFF SSTL15 DCI_S	0.397	0.397	0.417	0.397	0.768	0.768	0.822	0.768	0.847	0.847	0.912	0.847	ns
DIFF SSTL15 F	0.404	0.404	0.417	0.404	0.424	0.424	0.445	0.424	0.551	0.551	0.577	0.551	ns
DIFF SSTL15 M	0.404	0.404	0.417	0.404	0.554	0.554	0.585	0.554	0.639	0.639	0.677	0.639	ns
DIFF SSTL15 S	0.404	0.404	0.417	0.404	0.767	0.767	0.817	0.767	0.813	0.813	0.867	0.813	ns
DIFF SSTL18 I DCI_F	0.320	0.320	0.336	0.320	0.445	0.445	0.461	0.445	0.566	0.566	0.595	0.566	ns
DIFF SSTL18 I DCI_M	0.320	0.320	0.336	0.320	0.554	0.554	0.585	0.554	0.644	0.644	0.683	0.644	ns
DIFF SSTL18 I DCI_S	0.320	0.320	0.336	0.320	0.762	0.762	0.818	0.762	0.837	0.837	0.899	0.837	ns
DIFF SSTL18 I F	0.316	0.316	0.336	0.316	0.454	0.454	0.476	0.454	0.578	0.578	0.608	0.578	ns
DIFF SSTL18 I M	0.316	0.316	0.336	0.316	0.571	0.571	0.603	0.571	0.652	0.652	0.692	0.652	ns
DIFF SSTL18 I S	0.316	0.316	0.336	0.316	0.782	0.782	0.835	0.782	0.816	0.816	0.870	0.816	ns
HSLVDCI_15_F	0.393	0.393	0.415	0.393	0.425	0.425	0.443	0.425	0.548	0.548	0.579	0.548	ns
HSLVDCI_15_M	0.393	0.393	0.415	0.393	0.552	0.552	0.581	0.552	0.644	0.644	0.684	0.644	ns
HSLVDCI_15_S	0.393	0.393	0.415	0.393	0.748	0.748	0.802	0.748	0.827	0.827	0.890	0.827	ns
HSLVDCI_18_F	0.424	0.424	0.447	0.424	0.445	0.445	0.461	0.445	0.566	0.566	0.595	0.566	ns
HSLVDCI_18_M	0.424	0.424	0.447	0.424	0.567	0.567	0.598	0.567	0.658	0.658	0.699	0.658	ns

Table 24: IOB High Performance (HP) Switching Characteristics (Cont'd)

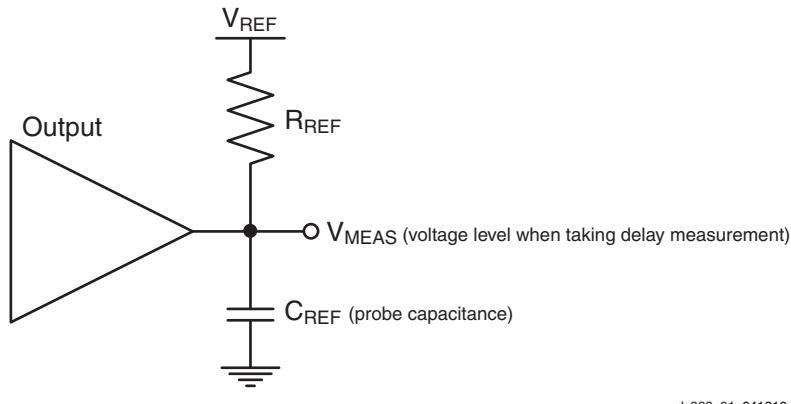
I/O Standards	T _{INBUF_DELAY_PAD_I}			T _{OUTBUF_DELAY_O_PAD}			T _{OUTBUF_DELAY_TD_PAD}			Units
	0.90V	0.85V	0.72V	0.90V	0.85V	0.72V	0.90V	0.85V	0.72V	
	-3	-2	-1	-2	-3	-2	-1	-2	-3	
HSLVDCI_18_S	0.424	0.424	0.447	0.424	0.761	0.761	0.817	0.761	0.836	0.836 ns
HSTL_I_12_F	0.378	0.378	0.399	0.378	0.423	0.423	0.443	0.423	0.553	0.553 ns
HSTL_I_12_M	0.378	0.378	0.399	0.378	0.551	0.551	0.582	0.551	0.642	0.642 ns
HSTL_I_12_S	0.378	0.378	0.399	0.378	0.750	0.750	0.799	0.750	0.813	0.813 ns
HSTL_I_18_F	0.322	0.322	0.339	0.322	0.456	0.456	0.474	0.456	0.576	0.576 ns
HSTL_I_18_M	0.322	0.322	0.339	0.322	0.569	0.569	0.602	0.569	0.653	0.653 ns
HSTL_I_18_S	0.322	0.322	0.339	0.322	0.781	0.781	0.833	0.781	0.816	0.816 ns
HSTL_I_DCI_12_F	0.378	0.378	0.399	0.378	0.406	0.406	0.429	0.406	0.534	0.534 ns
HSTL_I_DCI_12_M	0.378	0.378	0.399	0.378	0.556	0.556	0.586	0.556	0.654	0.654 ns
HSTL_I_DCI_12_S	0.378	0.378	0.399	0.378	0.754	0.754	0.803	0.754	0.842	0.842 ns
HSTL_I_DCI_18_F	0.321	0.321	0.339	0.321	0.445	0.445	0.461	0.445	0.566	0.566 ns
HSTL_I_DCI_18_M	0.321	0.321	0.339	0.321	0.554	0.554	0.585	0.554	0.643	0.643 ns
HSTL_I_DCI_18_S	0.321	0.321	0.339	0.321	0.761	0.761	0.817	0.761	0.836	0.836 ns
HSTL_I_DCI_F	0.393	0.393	0.415	0.393	0.431	0.431	0.445	0.431	0.555	0.555 ns
HSTL_I_DCI_M	0.393	0.393	0.415	0.393	0.552	0.552	0.581	0.552	0.644	0.644 ns
HSTL_I_DCI_S	0.393	0.393	0.415	0.393	0.766	0.766	0.821	0.766	0.847	0.847 ns
HSTL_I_F	0.378	0.378	0.399	0.378	0.423	0.423	0.443	0.423	0.549	0.549 ns
HSTL_I_M	0.378	0.378	0.399	0.378	0.554	0.554	0.585	0.554	0.640	0.640 ns
HSTL_I_S	0.378	0.378	0.399	0.378	0.766	0.766	0.816	0.766	0.811	0.811 ns
HSUL_12_DCI_F	0.378	0.378	0.399	0.378	0.425	0.425	0.443	0.425	0.558	0.558 ns
HSUL_12_DCI_M	0.378	0.378	0.399	0.378	0.556	0.556	0.586	0.556	0.654	0.654 ns
HSUL_12_DCI_S	0.378	0.378	0.399	0.378	0.736	0.736	0.784	0.736	0.821	0.821 ns
HSUL_12_F	0.378	0.378	0.399	0.378	0.412	0.412	0.430	0.412	0.538	0.538 ns
HSUL_12_M	0.378	0.378	0.399	0.378	0.551	0.551	0.582	0.551	0.642	0.642 ns
HSUL_12_S	0.378	0.378	0.399	0.378	0.750	0.750	0.799	0.750	0.813	0.813 ns
LVCMOS12_F_2	0.512	0.512	0.555	0.512	0.672	0.672	0.692	0.672	0.898	0.898 ns
LVCMOS12_F_4	0.512	0.512	0.555	0.512	0.504	0.504	0.521	0.504	0.664	0.664 ns
LVCMOS12_F_6	0.512	0.512	0.555	0.512	0.485	0.485	0.507	0.485	0.634	0.634 ns
LVCMOS12_F_8	0.512	0.512	0.555	0.512	0.465	0.465	0.489	0.465	0.611	0.611 ns
LVCMOS12_M_2	0.512	0.512	0.555	0.512	0.708	0.708	0.727	0.708	0.916	0.916 ns
LVCMOS12_M_4	0.512	0.512	0.555	0.512	0.550	0.550	0.573	0.550	0.664	0.664 ns
LVCMOS12_M_6	0.512	0.512	0.555	0.512	0.527	0.527	0.554	0.527	0.622	0.622 ns
LVCMOS12_M_8	0.512	0.512	0.555	0.512	0.540	0.540	0.571	0.540	0.614	0.614 ns
LVCMOS12_S_2	0.512	0.512	0.555	0.512	0.767	0.767	0.803	0.767	0.990	0.990 ns
LVCMOS12_S_4	0.512	0.512	0.555	0.512	0.666	0.666	0.704	0.666	0.803	0.803 ns
LVCMOS12_S_6	0.512	0.512	0.555	0.512	0.657	0.657	0.695	0.657	0.732	0.732 ns
LVCMOS12_S_8	0.512	0.512	0.555	0.512	0.708	0.708	0.761	0.708	0.745	0.745 ns
LVCMOS15_F_12	0.414	0.414	0.445	0.414	0.500	0.500	0.522	0.500	0.647	0.647 ns
LVCMOS15_F_2	0.414	0.414	0.445	0.414	0.702	0.702	0.722	0.702	0.919	0.919 ns
LVCMOS15_F_4	0.414	0.414	0.445	0.414	0.579	0.579	0.601	0.579	0.755	0.755 ns
LVCMOS15_F_6	0.414	0.414	0.445	0.414	0.547	0.547	0.569	0.547	0.711	0.711 ns

Table 24: IOB High Performance (HP) Switching Characteristics (Cont'd)

I/O Standards	T _{INBUF_DELAY_PAD_I}			T _{OUTBUF_DELAY_O_PAD}			T _{OUTBUF_DELAY_TD_PAD}			Units			
	0.90V	0.85V	0.72V	0.90V	0.85V	0.72V	0.90V	0.85V	0.72V				
	-3	-2	-1	-2	-3	-2	-1	-2	-3				
LVCMOS15_F_8	0.414	0.414	0.445	0.414	0.518	0.518	0.538	0.518	0.686	0.686	0.703	0.686	ns
LVCMOS15_M_12	0.414	0.414	0.445	0.414	0.607	0.607	0.644	0.607	0.637	0.637	0.676	0.637	ns
LVCMOS15_M_2	0.414	0.414	0.445	0.414	0.741	0.741	0.770	0.741	0.938	0.938	0.962	0.938	ns
LVCMOS15_M_4	0.414	0.414	0.445	0.414	0.625	0.625	0.651	0.625	0.754	0.754	0.786	0.754	ns
LVCMOS15_M_6	0.414	0.414	0.445	0.414	0.576	0.576	0.604	0.576	0.674	0.674	0.710	0.674	ns
LVCMOS15_M_8	0.414	0.414	0.445	0.414	0.568	0.568	0.601	0.568	0.639	0.639	0.681	0.639	ns
LVCMOS15_S_12	0.414	0.414	0.445	0.414	0.788	0.788	0.855	0.788	0.695	0.695	0.733	0.695	ns
LVCMOS15_S_2	0.414	0.414	0.445	0.414	0.829	0.829	0.864	0.829	1.039	1.039	1.079	1.039	ns
LVCMOS15_S_4	0.414	0.414	0.445	0.414	0.687	0.687	0.725	0.687	0.813	0.813	0.851	0.813	ns
LVCMOS15_S_6	0.414	0.414	0.445	0.414	0.671	0.671	0.710	0.671	0.726	0.726	0.763	0.726	ns
LVCMOS15_S_8	0.414	0.414	0.445	0.414	0.704	0.704	0.755	0.704	0.721	0.721	0.758	0.721	ns
LVCMOS18_F_12	0.418	0.418	0.445	0.418	0.573	0.573	0.601	0.573	0.731	0.731	0.769	0.731	ns
LVCMOS18_F_2	0.418	0.418	0.445	0.418	0.739	0.739	0.760	0.739	0.945	0.945	0.971	0.945	ns
LVCMOS18_F_4	0.418	0.418	0.445	0.418	0.609	0.609	0.630	0.609	0.778	0.778	0.802	0.778	ns
LVCMOS18_F_6	0.418	0.418	0.445	0.418	0.603	0.603	0.633	0.603	0.781	0.781	0.808	0.781	ns
LVCMOS18_F_8	0.418	0.418	0.445	0.418	0.573	0.573	0.600	0.573	0.733	0.733	0.767	0.733	ns
LVCMOS18_M_12	0.418	0.418	0.445	0.418	0.640	0.640	0.678	0.640	0.670	0.670	0.709	0.670	ns
LVCMOS18_M_2	0.418	0.418	0.445	0.418	0.798	0.798	0.822	0.798	0.991	0.991	1.016	0.991	ns
LVCMOS18_M_4	0.418	0.418	0.445	0.418	0.664	0.664	0.693	0.664	0.798	0.798	0.836	0.798	ns
LVCMOS18_M_6	0.418	0.418	0.445	0.418	0.629	0.629	0.663	0.629	0.735	0.735	0.775	0.735	ns
LVCMOS18_M_8	0.418	0.418	0.445	0.418	0.626	0.626	0.661	0.626	0.705	0.705	0.746	0.705	ns
LVCMOS18_S_12	0.418	0.418	0.445	0.418	0.795	0.795	0.861	0.795	0.683	0.683	0.721	0.683	ns
LVCMOS18_S_2	0.418	0.418	0.445	0.418	0.862	0.862	0.897	0.862	1.076	1.076	1.098	1.076	ns
LVCMOS18_S_4	0.418	0.418	0.445	0.418	0.716	0.716	0.758	0.716	0.829	0.829	0.872	0.829	ns
LVCMOS18_S_6	0.418	0.418	0.445	0.418	0.682	0.682	0.724	0.682	0.724	0.724	0.762	0.724	ns
LVCMOS18_S_8	0.418	0.418	0.445	0.418	0.707	0.707	0.760	0.707	0.709	0.709	0.745	0.709	ns
LVDCI_15_F	0.425	0.425	0.462	0.425	0.426	0.426	0.443	0.426	0.548	0.548	0.581	0.548	ns
LVDCI_15_M	0.425	0.425	0.462	0.425	0.553	0.553	0.582	0.553	0.645	0.645	0.685	0.645	ns
LVDCI_15_S	0.425	0.425	0.462	0.425	0.749	0.749	0.803	0.749	0.821	0.821	0.890	0.821	ns
LVDCI_18_F	0.414	0.414	0.447	0.414	0.441	0.441	0.459	0.441	0.560	0.560	0.589	0.560	ns
LVDCI_18_M	0.414	0.414	0.447	0.414	0.554	0.554	0.585	0.554	0.644	0.644	0.683	0.644	ns
LVDCI_18_S	0.414	0.414	0.447	0.414	0.760	0.760	0.818	0.760	0.837	0.837	0.899	0.837	ns
LVDS	0.539	0.539	0.620	0.539	0.626	0.626	0.662	0.626	960.447	960.447	960.447	960.447	ns
MIPI_DPHY_DCI_HS	0.386	0.386	0.415	0.386	0.502	0.502	0.522	0.502	N/A	N/A	N/A	N/A	ns
MIPI_DPHY_DCI_LP	8.438	8.438	8.792	8.438	0.914	0.914	0.937	0.914	N/A	N/A	N/A	N/A	ns
POD10_DCI_F	0.408	0.408	0.430	0.408	0.425	0.425	0.444	0.425	0.555	0.555	0.584	0.555	ns
POD10_DCI_M	0.408	0.408	0.430	0.408	0.542	0.542	0.571	0.542	0.640	0.640	0.681	0.640	ns
POD10_DCI_S	0.408	0.408	0.430	0.408	0.754	0.754	0.815	0.754	0.850	0.850	0.917	0.850	ns
POD10_F	0.407	0.407	0.430	0.407	0.438	0.438	0.459	0.438	0.569	0.569	0.601	0.569	ns
POD10_M	0.407	0.407	0.430	0.407	0.538	0.538	0.568	0.538	0.630	0.630	0.667	0.630	ns
POD10_S	0.407	0.407	0.430	0.407	0.766	0.766	0.821	0.766	0.836	0.836	0.894	0.836	ns

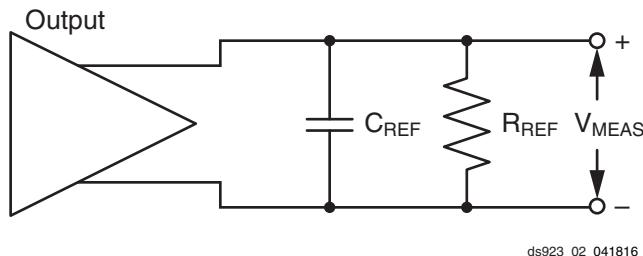
Output Delay Measurement Methodology

Output delays are measured with short output traces. Standard termination was used for all testing. The propagation delay of the trace is characterized separately and subtracted from the final measurement, and is therefore not included in the generalized test setups shown in [Figure 1](#) and [Figure 2](#).



ds923_01_041816

Figure 1: Single-Ended Test Setup



ds923_02_041816

Figure 2: Differential Test Setup

Parameters V_{REF} , R_{REF} , C_{REF} , and V_{MEAS} fully describe the test conditions for each I/O standard. The most accurate prediction of propagation delay in any given application can be obtained through IBIS simulation, using this method:

1. Simulate the output driver of choice into the generalized test setup using values from [Table 27](#).
2. Record the time to V_{MEAS} .
3. Simulate the output driver of choice into the actual PCB trace and load using the appropriate IBIS model or capacitance value to represent the load.
4. Record the time to V_{MEAS} .
5. Compare the results of [step 2](#) and [step 4](#). The increase or decrease in delay yields the actual propagation delay of the PCB trace.

Table 27: Output Delay Measurement Methodology

Description	I/O Standard Attribute	R _{REF} (Ω)	C _{REF} ⁽¹⁾ (pF)	V _{MEAS} (V)	V _{REF} (V)
LVC MOS, 1.2V	LVC MOS12	1M	0	0.6	0
LVC MOS, 1.5V	LVC MOS15	1M	0	0.75	0
LVC MOS, 1.8V	LVC MOS18	1M	0	0.9	0
LVDCI, HSLVDCI, 1.5V	LVDCI_15, HSLVDCI_15	50	0	V _{REF}	0.75
LVDCI, HSLVDCI, 1.8V	LVDCI_15, HSLVDCI_18	50	0	V _{REF}	0.9
HSTL (high-speed transceiver logic), class I, 1.2V	HSTL_I_12	50	0	V _{REF}	0.6
HSTL, class I, 1.5V	HSTL_I	50	0	V _{REF}	0.75
HSTL, class I, 1.8V	HSTL_I_18	50	0	V _{REF}	0.9
HSUL (high-speed unterminated logic), 1.2V	HSUL_12	50	0	V _{REF}	0.6
SSTL12 (stub series terminated logic), 1.2V	SSTL12	50	0	V _{REF}	0.6
SSTL135, 1.35V	SSTL135	50	0	V _{REF}	0.675
SSTL15, 1.5V	SSTL15	50	0	V _{REF}	0.75
SSTL18, class I, 1.8V	SSTL18_I	50	0	V _{REF}	0.9
POD10, 1.0V	POD10	50	0	V _{REF}	1.0
POD12, 1.2V	POD12	50	0	V _{REF}	1.2
DIFF_HSTL, class I, 1.2V	DIFF_HSTL_I_12	50	0	V _{REF}	0.6
DIFF_HSTL, class I, 1.5V	DIFF_HSTL_I	50	0	V _{REF}	0.75
DIFF_HSTL, class I, 1.8V	DIFF_HSTL_I_18	50	0	V _{REF}	0.9
DIFF_HSUL, 1.2V	DIFF_HSUL_12	50	0	V _{REF}	0.6
DIFF_SSTL12, 1.2V	DIFF_SSTL12	50	0	V _{REF}	0.6
DIFF_SSTL135, 1.35V	DIFF_SSTL135	50	0	V _{REF}	0.675
DIFF_SSTL15, 1.5V	DIFF_SSTL15	50	0	V _{REF}	0.75
DIFF_SSTL18, 1.8V	DIFF_SSTL18_I	50	0	V _{REF}	0.9
DIFF_POD10, 1.0V	DIFF_POD10	50	0	V _{REF}	1.0
DIFF_POD12, 1.2V	DIFF_POD12	50	0	V _{REF}	1.2
LVDS (low-voltage differential signaling), 1.8V	LVDS	100	0	0 ⁽²⁾	0
SUB_LVDS, 1.8V	SUB_LVDS	100	0	0 ⁽²⁾	0
MIPI D-PHY (high speed) 1.2V	MIPI_DPHY_DC1_HS	100	0	0 ⁽²⁾	0
MIPI D-PHY (low power) 1.2V	MIPI_DPHY_DC1_LP	1M	0	0.6	0

Notes:

1. C_{REF} is the capacitance of the probe, nominally 0 pF.
2. The value given is the differential output voltage.

MMCM Switching Characteristics

Table 33: MMCM Specification

Symbol	Description	Speed Grade and V_{CCINT} Operating Voltages			Units	
		0.90V	0.85V	0.72V		
		-3	-2	-1		
MMCM_F _{INMAX}	Maximum input clock frequency.	1066	933	800	MHz	
MMCM_F _{INMIN}	Minimum input clock frequency.	10	10	10	MHz	
MMCM_F _{INJITTER}	Maximum input clock period jitter.	< 20% of clock input period or 1 ns Max				
MMCM_F _{INDUTY}	Input duty cycle range: 10–49 MHz.	25–75			%	
	Input duty cycle range: 50–199 MHz.	30–70			%	
	Input duty cycle range: 200–399 MHz.	35–65			%	
	Input duty cycle range: 400–499 MHz.	40–60			%	
	Input duty cycle range: >500 MHz.	45–55			%	
MMCM_F _{MIN_PSCLK}	Minimum dynamic phase shift clock frequency.	0.01	0.01	0.01	MHz	
MMCM_F _{MAX_PSCLK}	Maximum dynamic phase shift clock frequency.	550	500	450	MHz	
MMCM_F _{VCOMIN}	Minimum MMCM VCO frequency.	800	800	800	MHz	
MMCM_F _{VCOMAX}	Maximum MMCM VCO frequency.	1600	1600	1600	MHz	
MMCM_F _{BANDWIDTH}	Low MMCM bandwidth at typical.(1)	1.00	1.00	1.00	MHz	
	High MMCM bandwidth at typical.(1)	4.00	4.00	4.00	MHz	
MMCM_T _{STATPHAOFFSET}	Static phase offset of the MMCM outputs.(2)	0.12	0.12	0.12	ns	
MMCM_T _{OUTJITTER}	MMCM output jitter.	Note 3				
MMCM_T _{OUTDUTY}	MMCM output clock duty cycle precision.(4)	0.165	0.20	0.20	0.20	ns
MMCM_T _{LOCKMAX}	MMCM maximum lock time for MMCM_F _{PFDMIN} .	100	100	100	100	μs
MMCM_F _{OUTMAX}	MMCM maximum output frequency.	891	775	667	725	MHz
MMCM_F _{OUTMIN}	MMCM minimum output frequency.(4)(5)	6.25	6.25	6.25	6.25	MHz
MMCM_T _{EXTFDVAR}	External clock feedback variation.	< 20% of clock input period or 1 ns Max				
MMCM_RST _{MINPULSE}	Minimum reset pulse width.	5.00	5.00	5.00	5.00	ns
MMCM_F _{PFDMAX}	Maximum frequency at the phase frequency detector.	550	500	450	500	MHz
MMCM_F _{PFDMIN}	Minimum frequency at the phase frequency detector.	10	10	10	10	MHz
MMCM_T _{FBDELAY}	Maximum delay in the feedback path.	5 ns Max or one clock cycle				
MMCM_F _{DPRCLK_MAX}	Maximum DRP clock frequency	250	250	250	250	MHz

Notes:

1. The MMCM does not filter typical spread-spectrum input clocks because they are usually far below the bandwidth filter frequencies.
2. The static offset is measured between any MMCM outputs with identical phase.
3. Values for this parameter are available in the Clocking Wizard.
4. Includes global clock buffer.
5. Calculated as $F_{vco}/128$ assuming output duty cycle is 50%.

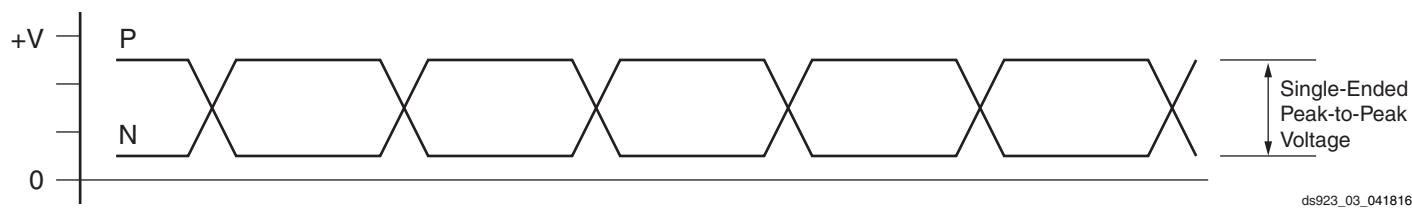


Figure 3: Single-Ended Peak-to-Peak Voltage

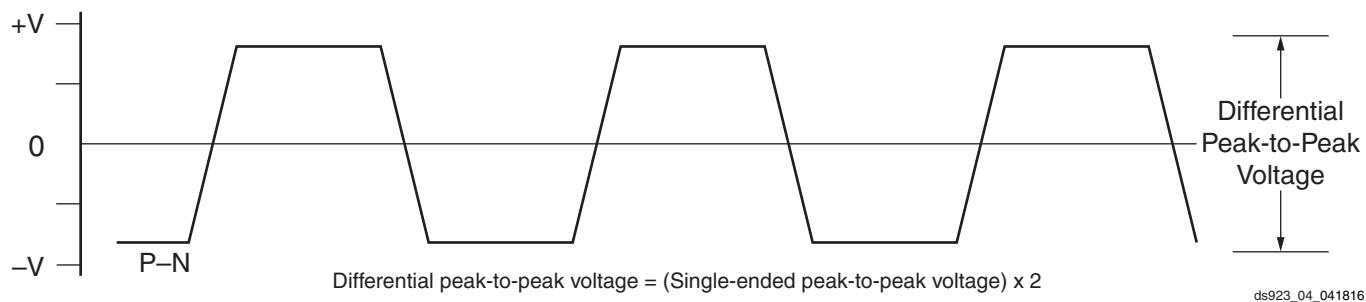


Figure 4: Differential Peak-to-Peak Voltage

[Table 42](#) and [Table 43](#) summarize the DC specifications of the clock input of the GTY transceivers in Virtex UltraScale+ FPGAs. Consult www.xilinx.com/products/technology/high-speed-serial for further details.

Table 42: GTY Transceiver Clock DC Input Level Specification

Symbol	DC Parameter	Min	Typ	Max	Units
V_{IDIFF}	Differential peak-to-peak input voltage	250	—	2000	mV
R_{IN}	Differential input resistance	—	100	—	Ω
C_{EXT}	Required external AC coupling capacitor	—	10	—	nF

Table 43: GTY Transceiver Clock Output Level Specification

Symbol	Description	Conditions	Min	Typ	Max	Units
V_{OL}	Output high voltage for P and N	$R_T = 100\Omega$ across P and N signals	100	—	330	mV
V_{OH}	Output low voltage for P and N	$R_T = 100\Omega$ across P and N signals	500	—	700	mV
V_{DDOUT}	Differential output voltage (P-N), P = High (N-P), N = High	$R_T = 100\Omega$ across P and N signals	300	—	430	mV
V_{CMOUT}	Common mode voltage	$R_T = 100\Omega$ across P and N signals	300	—	500	mV

Table 45: GTY Transceiver Dynamic Reconfiguration Port (DRP) Switching Characteristics

Symbol	Description	All Speed Grades			Units
$F_{GTYDRPCLK}$	GTYDRPCLK maximum frequency.	250			MHz

Table 46: GTY Transceiver Reference Clock Switching Characteristics

Symbol	Description	Conditions	All Speed Grades			Units
			Min	Typ	Max	
F_{GCLK}	Reference clock frequency range.		60	—	820	MHz
T_{RCLK}	Reference clock rise time.	20% – 80%	—	200	—	ps
T_{FCLK}	Reference clock fall time.	80% – 20%	—	200	—	ps
T_{DCREF}	Reference clock duty cycle.	Transceiver PLL only	40	50	60	%

Table 47: GTY Transceiver Reference Clock Oscillator Selection Phase Noise Mask⁽¹⁾

Symbol	Description	Offset Frequency	Min	Typ	Max	Units
$QPLL_{REFCLKMASK}$	QPLL0/QPLL1 reference clock select phase noise mask at REFCLK frequency = 156.25 MHz.	10 kHz	—	—	-112	dBc/Hz
		100 kHz	—	—	-128	
		1 MHz	—	—	-145	
	QPLL0/QPLL1 reference clock select phase noise mask at REFCLK frequency = 312.5 MHz.	10 kHz	—	—	-103	dBc/Hz
		100 kHz	—	—	-123	
		1 MHz	—	—	-143	
	QPLL0/QPLL1 reference clock select phase noise mask at REFCLK frequency = 625 MHz.	10 kHz	—	—	-98	dBc/Hz
		100 kHz	—	—	-117	
		1 MHz	—	—	-140	
$CPLL_{REFCLKMASK}$	CPLL reference clock select phase noise mask at REFCLK frequency = 156.25 MHz.	10 kHz	—	—	-112	dBc/Hz
		100 kHz	—	—	-128	
		1 MHz	—	—	-145	
		50 MHz	—	—	-145	
	CPLL reference clock select phase noise mask at REFCLK frequency = 312.5 MHz.	10 kHz	—	—	-103	dBc/Hz
		100 kHz	—	—	-123	
		1 MHz	—	—	-143	
		50 MHz	—	—	-145	
	CPLL reference clock select phase noise mask at REFCLK frequency = 625 MHz.	10 kHz	—	—	-98	dBc/Hz
		100 kHz	—	—	-117	
		1 MHz	—	—	-140	
		50 MHz	—	—	-144	

Notes:

- For reference clock frequencies not in this table, use the phase-noise mask for the nearest reference clock frequency.

Table 50: GTY Transceiver Transmitter Switching Characteristics

Symbol	Description	Condition	Min	Typ	Max	Units
F _{GTYTX}	Serial data rate range		0.500	–	F _{GTYMAX}	Gb/s
T _{RTX}	TX rise time	20%–80%	–	21	–	ps
T _{FTX}	TX fall time	80%–20%	–	21	–	ps
T _{LSSKEW}	TX lane-to-lane skew ⁽¹⁾		–	–	500.00	ps
T _{J32.75}	Total jitter ⁽²⁾⁽⁴⁾	32.75 Gb/s	–	–	0.35	UI
D _{J32.75}	Deterministic jitter ⁽²⁾⁽⁴⁾		–	–	0.19	UI
T _{J28.21}	Total jitter ⁽²⁾⁽⁴⁾	28.21 Gb/s	–	–	0.28	UI
D _{J28.21}	Deterministic jitter ⁽²⁾⁽⁴⁾		–	–	0.17	UI
T _{J16.375}	Total jitter ⁽²⁾⁽⁴⁾	16.375 Gb/s	–	–	0.28	UI
D _{J16.375}	Deterministic jitter ⁽²⁾⁽⁴⁾		–	–	0.17	UI
T _{J15.0}	Total jitter ⁽²⁾⁽⁴⁾	15.0 Gb/s	–	–	0.28	UI
D _{J15.0}	Deterministic jitter ⁽²⁾⁽⁴⁾		–	–	0.17	UI
T _{J14.1}	Total jitter ⁽²⁾⁽⁴⁾	14.1 Gb/s	–	–	0.28	UI
D _{J14.1}	Deterministic jitter ⁽²⁾⁽⁴⁾		–	–	0.17	UI
T _{J14.1}	Total jitter ⁽²⁾⁽⁴⁾	14.025 Gb/s	–	–	0.28	UI
D _{J14.1}	Deterministic jitter ⁽²⁾⁽⁴⁾		–	–	0.17	UI
T _{J13.1}	Total jitter ⁽²⁾⁽⁴⁾	13.1 Gb/s	–	–	0.28	UI
D _{J13.1}	Deterministic jitter ⁽²⁾⁽⁴⁾		–	–	0.17	UI
T _{J12.5_QPLL}	Total jitter ⁽²⁾⁽⁴⁾	12.5 Gb/s	–	–	0.28	UI
D _{J12.5_QPLL}	Deterministic jitter ⁽²⁾⁽⁴⁾		–	–	0.17	UI
T _{J12.5_CPLL}	Total jitter ⁽³⁾⁽⁴⁾	12.5 Gb/s	–	–	0.33	UI
D _{J12.5_CPLL}	Deterministic jitter ⁽³⁾⁽⁴⁾		–	–	0.17	UI
T _{J11.3}	Total jitter ⁽²⁾⁽⁴⁾	11.3 Gb/s	–	–	0.28	UI
D _{J11.3}	Deterministic jitter ⁽²⁾⁽⁴⁾		–	–	0.17	UI
T _{J10.3125_QPLL}	Total jitter ⁽²⁾⁽⁴⁾	10.3125 Gb/s	–	–	0.28	UI
D _{J10.3125_QPLL}	Deterministic jitter ⁽²⁾⁽⁴⁾		–	–	0.17	UI
T _{J10.3125_CPLL}	Total jitter ⁽³⁾⁽⁴⁾	10.3125 Gb/s	–	–	0.33	UI
D _{J10.3125_CPLL}	Deterministic jitter ⁽³⁾⁽⁴⁾		–	–	0.17	UI
T _{J9.953_QPLL}	Total jitter ⁽²⁾⁽⁴⁾	9.953 Gb/s	–	–	0.28	UI
D _{J9.953_QPLL}	Deterministic jitter ⁽²⁾⁽⁴⁾		–	–	0.17	UI
T _{J9.953_CPLL}	Total jitter ⁽³⁾⁽⁴⁾	9.953 Gb/s	–	–	0.33	UI
D _{J9.953_CPLL}	Deterministic jitter ⁽³⁾⁽⁴⁾		–	–	0.17	UI
T _{J8.0}	Total jitter ⁽³⁾⁽⁴⁾	8.0 Gb/s	–	–	0.32	UI
D _{J8.0}	Deterministic jitter ⁽³⁾⁽⁴⁾		–	–	0.17	UI
T _{J6.6}	Total jitter ⁽³⁾⁽⁴⁾	6.6 Gb/s	–	–	0.30	UI
D _{J6.6}	Deterministic jitter ⁽³⁾⁽⁴⁾		–	–	0.15	UI
T _{J5.0}	Total jitter ⁽³⁾⁽⁴⁾	5.0 Gb/s	–	–	0.30	UI
D _{J5.0}	Deterministic jitter ⁽³⁾⁽⁴⁾		–	–	0.15	UI
T _{J4.25}	Total jitter ⁽³⁾⁽⁴⁾	4.25 Gb/s	–	–	0.30	UI
D _{J4.25}	Deterministic jitter ⁽³⁾⁽⁴⁾		–	–	0.15	UI

Table 50: GTY Transceiver Transmitter Switching Characteristics (Cont'd)

Symbol	Description	Condition	Min	Typ	Max	Units
T _{J3.20}	Total jitter ⁽³⁾⁽⁴⁾	3.20 Gb/s ⁽⁵⁾	—	—	0.20	UI
D _{J3.20}	Deterministic jitter ⁽³⁾⁽⁴⁾		—	—	0.10	UI
T _{J2.5}	Total jitter ⁽³⁾⁽⁴⁾	2.5 Gb/s ⁽⁶⁾	—	—	0.20	UI
D _{J2.5}	Deterministic jitter ⁽³⁾⁽⁴⁾		—	—	0.10	UI
T _{J1.25}	Total jitter ⁽³⁾⁽⁴⁾	1.25 Gb/s ⁽⁷⁾	—	—	0.15	UI
D _{J1.25}	Deterministic jitter ⁽³⁾⁽⁴⁾		—	—	0.06	UI
T _{J500}	Total jitter ⁽³⁾⁽⁴⁾	500 Mb/s ⁽⁸⁾	—	—	0.10	UI
D _{J500}	Deterministic jitter ⁽³⁾⁽⁴⁾		—	—	0.03	UI

Notes:

1. Using same REFCLK input with TX phase alignment enabled for up to four consecutive transmitters (one fully populated GTY Quad) at maximum line rate.
2. Using QPLL_FBDIV = 40, 20-bit internal data width. These values are NOT intended for protocol specific compliance determinations.
3. Using CPLL_FBDIV = 2, 20-bit internal data width. These values are NOT intended for protocol specific compliance determinations.
4. All jitter values are based on a bit-error ratio of 10^{-12} .
5. CPLL frequency at 3.2 GHz and TXOUT_DIV = 2.
6. CPLL frequency at 2.5 GHz and TXOUT_DIV = 2.
7. CPLL frequency at 2.5 GHz and TXOUT_DIV = 4.
8. CPLL frequency at 2.0 GHz and TXOUT_DIV = 8.

Table 51: GTY Transceiver Receiver Switching Characteristics

Symbol	Description	Condition	Min	Typ	Max	Units
F_{GTYRX}	Serial data rate		0.500	–	F_{GTYMAX}	Gb/s
R_{XSST}	Receiver spread-spectrum tracking ⁽¹⁾	Modulated at 33 kHz	-5000	–	0	ppm
R_{XRL}	Run length (CID)		–	–	256	UI
$R_{XPMMTOL}$	Data/REFCLK PPM offset tolerance	Bit rates ≤ 6.6 Gb/s	-1250	–	1250	ppm
		Bit rates > 6.6 Gb/s and ≤ 8.0 Gb/s	-700	–	700	ppm
		Bit rates > 8.0 Gb/s	-200	–	200	ppm
SJ Jitter Tolerance⁽²⁾						
$J_{T_SJ32.75}$	Sinusoidal jitter (QPLL) ⁽³⁾	32.75 Gb/s	0.25	–	–	UI
$J_{T_SJ28.21}$	Sinusoidal jitter (QPLL) ⁽³⁾	28.21 Gb/s	0.30	–	–	UI
$J_{T_SJ16.375}$	Sinusoidal jitter (QPLL) ⁽³⁾	16.375 Gb/s	0.30	–	–	UI
$J_{T_SJ15.0}$	Sinusoidal jitter (QPLL) ⁽³⁾	15.0 Gb/s	0.30	–	–	UI
$J_{T_SJ14.1}$	Sinusoidal jitter (QPLL) ⁽³⁾	14.1 Gb/s	0.30	–	–	UI
$J_{T_SJ13.1}$	Sinusoidal jitter (QPLL) ⁽³⁾	13.1 Gb/s	0.30	–	–	UI
$J_{T_SJ12.5}$	Sinusoidal jitter (QPLL) ⁽³⁾	12.5 Gb/s	0.30	–	–	UI
$J_{T_SJ11.3}$	Sinusoidal jitter (QPLL) ⁽³⁾	11.3 Gb/s	0.30	–	–	UI
$J_{T_SJ10.32_QPLL}$	Sinusoidal jitter (QPLL) ⁽³⁾	10.32 Gb/s	0.30	–	–	UI
$J_{T_SJ10.32_CPLL}$	Sinusoidal jitter (CPLL) ⁽³⁾	10.32 Gb/s	0.30	–	–	UI
$J_{T_SJ9.953_QPLL}$	Sinusoidal jitter (QPLL) ⁽³⁾	9.953 Gb/s	0.30	–	–	UI
$J_{T_SJ9.953_CPLL}$	Sinusoidal jitter (CPLL) ⁽³⁾	9.953 Gb/s	0.30	–	–	UI
$J_{T_SJ8.0}$	Sinusoidal jitter (CPLL) ⁽³⁾	8.0 Gb/s	0.42	–	–	UI
$J_{T_SJ6.6}$	Sinusoidal jitter (CPLL) ⁽³⁾	6.6 Gb/s	0.44	–	–	UI
$J_{T_SJ5.0}$	Sinusoidal jitter (CPLL) ⁽³⁾	5.0 Gb/s	0.44	–	–	UI
$J_{T_SJ4.25}$	Sinusoidal jitter (CPLL) ⁽³⁾	4.25 Gb/s	0.44	–	–	UI
$J_{T_SJ3.2}$	Sinusoidal jitter (CPLL) ⁽³⁾	3.2 Gb/s ⁽⁴⁾	0.45	–	–	UI
$J_{T_SJ2.5}$	Sinusoidal jitter (CPLL) ⁽³⁾	2.5 Gb/s ⁽⁵⁾	0.30	–	–	UI
$J_{T_SJ1.25}$	Sinusoidal jitter (CPLL) ⁽³⁾	1.25 Gb/s ⁽⁶⁾	0.30	–	–	UI
J_{T_SJ500}	Sinusoidal jitter (CPLL) ⁽³⁾	500 Mb/s ⁽⁷⁾	0.30	–	–	UI
SJ Jitter Tolerance with Stressed Eye⁽²⁾						
$J_{T_TJSE3.2}$	Total jitter with stressed eye ⁽⁸⁾	3.2 Gb/s	0.70	–	–	UI
		6.6 Gb/s	0.70	–	–	UI
$J_{T_TJSE6.6}$	Sinusoidal jitter with stressed eye ⁽⁸⁾	3.2 Gb/s	0.10	–	–	UI
		6.6 Gb/s	0.10	–	–	UI

Notes:

1. Using RXOUT_DIV = 1, 2, and 4.
2. All jitter values are based on a bit error ratio of 10^{-12} .
3. The frequency of the injected sinusoidal jitter is 80 MHz.
4. CPLL frequency at 3.2 GHz and RXOUT_DIV = 2.
5. CPLL frequency at 2.5 GHz and RXOUT_DIV = 2.
6. CPLL frequency at 2.5 GHz and RXOUT_DIV = 4.
7. CPLL frequency at 2.0 GHz and RXOUT_DIV = 8.
8. Composite jitter with RX equalizer enabled. DFE disabled.

Integrated Interface Block for 100G Ethernet MAC and PCS

More information and documentation on solutions using the integrated 100 Gb/s Ethernet block can be found at [UltraScale Integrated 100G Ethernet MAC/PCS](#). The *UltraScale Architecture and Product Overview* ([DS890](#)) lists how many blocks are in each Virtex UltraScale+ FPGA.

Table 56: Maximum Performance for 100G Ethernet Designs

Symbol	Description	Speed Grade and V _{CCINT} Operating Voltages				Units
		0.90V	0.85V		0.72V	
		-3	-2 ⁽¹⁾	-1	-2	
F _{TX_CLK}	Transmit clock	390.625	390.625	322.223	322.223	MHz
F _{RX_CLK}	Receive clock	390.625	390.625	322.223	322.223	MHz
F _{RX_SERDES_CLK}	Receive serializer/deserializer clock	390.625	390.625	322.223	322.223	MHz
F _{DRP_CLK}	Dynamic reconfiguration port clock	250.00	250.00	250.00	250.00	MHz

Notes:

1. The maximum clock frequency of 390.625 MHz only applies to the CAUI-10 interface. The maximum clock frequency for the CAUI-4 interface is 322.223 MHz.

Integrated Interface Block for PCI Express Designs

More information and documentation on solutions for PCI Express designs can be found at [PCI Express](#). The *UltraScale Architecture and Product Overview* ([DS890](#)) lists how many blocks are in each Virtex UltraScale+ FPGA.

Table 57: Maximum Performance for PCI Express Designs⁽¹⁾⁽²⁾

Symbol	Description	Speed Grade and V _{CCINT} Operating Voltages				Units
		0.90V	0.85V		0.72V	
		-3	-2	-1	-2	
F _{PIPECLK}	Pipe clock maximum frequency.	250.00	250.00	250.00	250.00	MHz
F _{CORECLK}	Core clock maximum frequency.	500.00	500.00	500.00	250.00	MHz
F _{DRPCLK}	DRP clock maximum frequency.	250.00	250.00	250.00	250.00	MHz
F _{MCAPCLK}	MCAP clock maximum frequency.	125.00	125.00	125.00	125.00	MHz

Notes:

1. PCI Express Gen4 operation is supported for x1, x2, x4, and x8 widths.
2. PCI Express Gen4 operation is supported in -3E, -2E, and -1I speed grades.

SYSMON I2C/PMBus Interfaces

Table 59: SYSMON I2C Fast Mode Interface Switching Characteristics⁽¹⁾

Symbol	Description	Min	Max	Units
T_{SMFCKL}	SCL Low time	1.3	–	μs
T_{SMFCKH}	SCL High time	0.6	–	μs
T_{SMFCKO}	SDAO clock-to-out delay	–	900	ns
T_{SMFDCK}	SDAI setup time	100	–	ns
F_{SMFCLK}	SCL clock frequency	–	400	kHz

Notes:

1. The test conditions are configured to the LVC MOS 1.8V I/O standard.

Table 60: SYSMON I2C Standard Mode Interface Switching Characteristics⁽¹⁾

Symbol	Description	Min	Max	Units
T_{SMSCKL}	SCL Low time	4.7	–	μs
T_{SMSCKH}	SCL High time	4.0	–	μs
T_{SMSCKO}	SDAO clock-to-out delay	–	3450	ns
T_{SMSDCK}	SDAI setup time	250	–	ns
F_{SMSCLK}	SCL clock frequency	–	100	kHz

Notes:

1. The test conditions are configured to the LVC MOS 1.8V I/O standard.

Table 61: Configuration Switching Characteristics (Cont'd)

Symbol	Description	Speed Grade and V_{CCINT} Operating Voltages				Units	
		0.90V	0.85V	0.72V			
		-3	-2	-1	-2		
SelectMAP Mode Programming Switching							
T_{SMDCCK}/T_{SMCCKD}	D[31:00] setup/hold.	XCVU3P, XCVU5P, XCVU7P, XCVU9P	4.0/0	4.0/0	4.0/0	5.0/0	ns, Min
		XCVU11P, XCVU13P	4.5/0	4.5/0	4.5/0	7.5/0	ns, Min
$T_{SMCSCK}/T_{SMCCKCS}$	CSI_B setup/hold.	XCVU3P, XCVU5P, XCVU7P, XCVU9P	4.0/0	4.0/0	4.0/0	5.0/0	ns, Min
		XCVU11P, XCVU13P	4.5/0	4.5/0	4.5/0	7.5/0	ns, Min
T_{SMWCCK}/T_{SMCCKW}	RDWR_B setup/hold.	XCVU3P, XCVU5P, XCVU7P, XCVU9P	10.0/0	10.0/0	10.0/0	11.0/0	ns, Min
		XCVU11P, XCVU13P	11.0/0	11.0/0	11.0/0	17.0/0	ns, Min
T_{SMCKSO}	CSO_B clock to out (330Ω pull-up resistor required).		7.0	7.0	7.0	7.0	ns, Max
T_{SMCO}	D[31:00] clock to out in readback.		8.0	8.0	8.0	8.0	ns, Max
F_{RBCK}	Readback frequency.	XCVU3P, XCVU5P, XCVU7P, XCVU9P	125	125	125	100	MHz, Max
		XCVU11P, XCVU13P	125	125	125	66	MHz, Max
Boundary-Scan Port Timing Specifications							
T_{TAPTCK}/T_{TCKTAP}	TMS and TDI setup/hold.	XCVU3P	3.0/ 2.0	3.0/ 2.0	3.0/ 2.0	3.0/ 2.0	ns, Min
		XCVU5P, XCVU7P, XCVU9P, XCVU11P, XCVU13P	8.5/ 2.0	8.5/ 2.0	8.5/ 2.0	8.5/ 2.0	ns, Min
T_{TCKTDO}	TCK falling edge to TDO output.	XCVU3P	7.0	7.0	7.0	7.0	ns, Max
		XCVU5P, XCVU7P, XCVU9P, XCVU11P, XCVU13P	15.0	15.0	15.0	15.0	ns, Max
F_{TCK}	TCK frequency.	XCVU3P	66	66	66	66	MHz, Max
		XCVU5P, XCVU7P, XCVU9P, XCVU11P, XCVU13P	20	20	20	20	MHz, Max
BPI Master Flash Mode Programming Switching							
T_{BPICCO}	A[28:00], RS[1:0], FCS_B, FOE_B, FWE_B, ADV_B clock to out.		10	10	10	10	ns, Max
T_{BPIDCC}/T_{BPICCD}	D[15:00] setup/hold.	XCVU3P, XCVU5P, XCVU7P, XCVU9P	4.0/0	4.0/0	4.0/0	5.0/0	ns, Min
		XCVU11P, XCVU13P	4.5/0	4.5/0	4.5/0	7.5/0	ns, Min
SPI Master Flash Mode Programming Switching							
T_{SPIDCC}/T_{SPICCD}	D[03:00] setup/hold.		3.0/0	3.0/0	3.0/0	4.0/0	ns, Min
T_{SPIDCC}/T_{SPICCD}	D[07:04] setup/hold.	XCVU3P, XCVU5P, XCVU7P, XCVU9P	4.0/0	4.0/0	4.0/0	5.0/0	ns, Min
		XCVU11P, XCVU13P	4.5/0	4.5/0	4.5/0	7.5/0	ns, Min
T_{SPICCM}	MOSI clock to out.		8.0	8.0	8.0	8.0	ns, Max
T_{SPICCF}	FCS_B clock to out.		8.0	8.0	8.0	8.0	ns, Max

Table 61: Configuration Switching Characteristics (Cont'd)

Symbol	Description	Speed Grade and V_{CCINT} Operating Voltages			Units
		0.90V	0.85V	0.72V	
		-3	-2	-1	
DNA Port Switching					
F_{DNACK}	DNA port frequency.	200	200	200	175 MHz, Max
STARTUPE3 Ports					
$T_{USRCLKO}$	STARTUPE3 USRCLKO input port to CCLK pin output delay.	0.25/ 6.00	0.25/ 6.50	0.25/ 7.50	0.25/ 9.00 ns, Min/Max
T_{DO}	DO[3:0] ports to D03-D00 pins output delay.	0.25/ 6.70	0.25/ 7.70	0.25/ 8.40	0.25/ 10.00 ns, Min/Max
T_{DTS}	DTS[3:0] ports to D03-D00 pins 3-state delays.	0.25/ 6.70	0.25/ 7.70	0.25/ 8.40	0.25/ 10.00 ns, Min/Max
T_{FCSBO}	FCSBO port to FCS_B pin output delay.	0.25/ 6.90	0.25/ 7.50	0.25/ 8.40	0.25/ 9.80 ns, Min/Max
T_{FCSBTS}	FCSBTS port to FCS_B pin 3-state delay.	0.25/ 6.90	0.25/ 7.50	0.25/ 8.40	0.25/ 9.80 ns, Min/Max
$T_{USRDONEO}$	USRDONEO port to DONE pin output delay.	0.25/ 8.60	0.25/ 9.40	0.25/ 10.50	0.25/ 12.10 ns, Min/Max
$T_{USRDONETS}$	USRDONETS port to DONE pin 3-state delay.	0.25/ 8.60	0.25/ 9.40	0.25/ 10.50	0.25/ 12.10 ns, Min/Max
T_{DI}	D03-D00 pins to DI[3:0] ports input delay.	0.5/ 2.6	0.5/ 3.1	0.5/ 3.5	0.5/ 4.0 ns, Min/Max
$F_{CFGMCLK}$	STARTUPE3 CFGMCLK output frequency.	50	50	50	50 MHz, Typ
$F_{CFGMCLKTOL}$	STARTUPE3 CFGMCLK output frequency tolerance.	± 15	± 15	± 15	± 15 %, Max
T_{DCI_MATCH}	Specifies a stall in the startup cycle until the digitally controlled impedance (DCI) match signals are asserted.	4	4	4	4 ms, Max

Notes:

- When the CCLK is sourced from the EMCCLK pin with a divide-by-one setting, the external EMCCLK must meet this duty-cycle requirement.